TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH238FK

3-to-8 Line Decoder

The TC7MH238FK is an advanced high speed CMOS 3-to-8 decoder fabricated with silicon gate $\rm C^2MOS$ technology.

It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs (Y0-Y7) will go high.

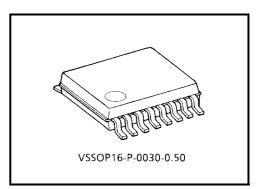
When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go low.

G1, $\overline{G}2A$ and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This

to the input pins without regard to the supply voltage. This device can be used to interface 5~V to 3~V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

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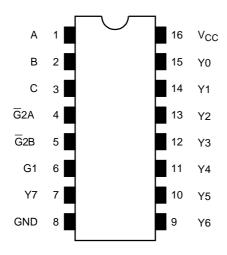


Weight: 0.02 g (typ.)

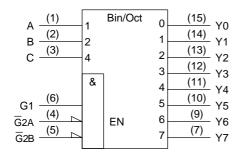
Features

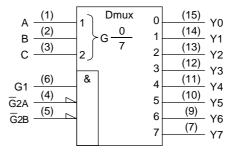
- High speed: $t_{pd} = 5.5 \text{ ns (typ.)} (V_{CC} = 5 \text{ V})$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_pLH \approx t_pHL$
- Wide operating voltage range: $V_{CC (opr)} = 2 \sim 5.5 \text{ V}$
- Pin and function compatible with 74ALS238

Pin Assignment (top view)



IEC Logic Symbol





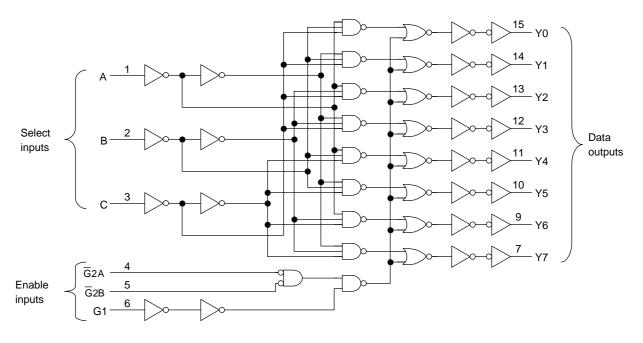
Truth Table

	Inputs					Outputs									
	Enable		Select		Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7	Selected Output		
G1	G ₂ A	G ₂ B	С	В	Α	10	Y I	12	13	14	15	10	17		
L	Х	Х	Х	Х	Х	L	L	L	L	L	L	L	L	None	
Х	Н	Х	Х	Х	Х	L	L	L	L	L	L	L	Ш	None	
Х	Х	Η	Х	Х	Х	L	L	L	L	L	L	L	Ш	None	
Н	L	Ш	Ш	Ш	Ш	Н	L	L	L	L	L	L	Ш	Y0	
Н	L	Ш	Ш	Ш	Ι	L	Н	L	L	L	L	L	Ш	Y1	
Н	L	Ш	Ш	Η	Ш	L	L	Н	L	L	L	L	Ш	Y2	
Н	L	L	L	Н	Н	L	L	L	Н	L	L	L	L	Y3	
Н	L	L	Н	L	L	L	L	L	L	Н	L	L	L	Y4	
Н	L	L	Н	L	Н	L	L	Ĺ	Ĺ	L	Н	L	L	Y5	
Н	L	L	Н	Н	L	L	L	Ĺ	L	L	L	Н	L	Y6	
Н	L	L	Н	Н	Н	L	L	Ĺ	L	L	L	L	Н	Y7	

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X: Don't care

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5~7.0	V	
DC input voltage	V _{IN}	-0.5~7.0	V	
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V	
Input diode current	I _{IK}	-20	mA	
Output diode current	lok	±20	mA	
DC output current	lout	±25	mA	
DC V _{CC} /ground current	Icc	±75	mA	
Power dissipation	P _D	180	mW	
Storage temperature	T _{stg}	-65~150	°C	

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0~5.5	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~V _{CC}	V	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	$0 \sim 100 \text{ (V}_{CC} = 3.3 \pm 0.3 \text{ V)}$	ns/V	
input noe and fail time	αι/αν	$0 \sim 20 \ (V_{CC} = 5 \pm 0.5 \ V)$	113/ V	

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition			-	Га = 25°C		Ta = -4	Lloit	
Characte	Ondiacteristics		rest Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
			_		2.0	1.50	_	_	1.50	_	V
Input voltage	High level	V _{IH}			3.0~5.5	V _{CC} × 0.7	_	_	V _{CC} × 0.7		
input voitage					2.0		_	0.50	_	0.50	
	Low level	V _{IL}		_	3.0~5.5	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	
	High level	Voн	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9	_	
					3.0	2.9	3.0	_	2.9	_	
					4.5	4.4	4.5	_	4.4	_	
				$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_	
Output voltage				$I_{OH} = -8 \text{ mA}$	4.5	3.94			3.80	_	V
Output voltage	Low level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	Ι _{ΟL} = 50 μΑ	2.0		0	0.1	_	0.1	
					3.0		0	0.1	_	0.1	
					4.5		0	0.1	_	0.1	
				I _{OL} = 4 mA	3.0	_		0.36	_	0.44	
				I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44	
Input leakage current		I _{IN}	V _{IN} = 5.5 V or GND		0~5.5			±0.1	_	±1.0	μΑ
Quiescent supply current		Icc	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	_	40.0	μΑ

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -4	Unit	
Characteristics	Symbol	rest Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Unit
	t _{pLH}		3.3 ± 0.3	15	_	8.0	12.3	1.0	14.5	ns
Propagation delay time				50	_	10.5	15.8	1.0	18.0	
(A, B, C-Y)	tpHL	_	5.0 ± 0.5	15		5.5	8.1	1.0	9.5	113
			5.0 ± 0.5	50		7.0	10.1	1.0	11.5	
	t _{pLH} t _{pHL}	_	3.3 ± 0.3	15		8.1	12.8	1.0	15.0	ns
Propagation delay time				50		10.6	16.3	1.0	18.5	
Propagation delay time (G1-Y)			5.0 ± 0.5	15		5.4	8.1	1.0	9.5	
			3.0 ± 0.3	50		6.9	10.1	1.0	14.5 18.0 9.5 11.5 15.0 18.5	
	^t pLH ^t pHL	_	3.3 ± 0.3	15		8.1	12.3	1.0	14.5	
Propagation delay time				50	_	10.6	15.8	1.0	18.0	
(G 2 -Y)			5.0 ± 0.5	15	_	5.7	8.1	1.0	9.5	
				50		7.2	10.1	1.0	11.5	
Input capacitance	C _{IN}	-	_			4	_	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)	_	37		_	_	pF

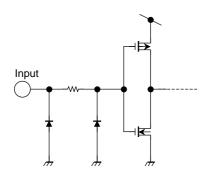
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

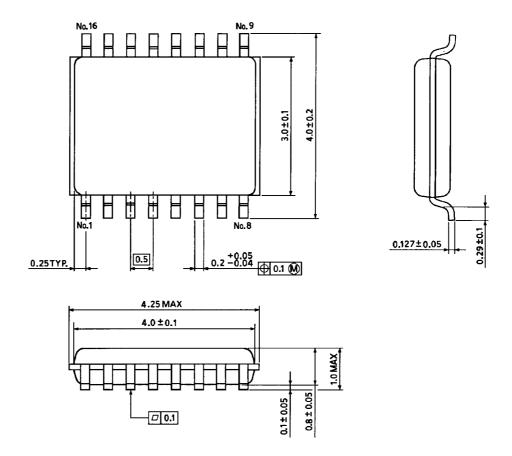
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Input Equivalent Circuit



Package Dimensions

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Weight: 0.02 g (typ.)

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